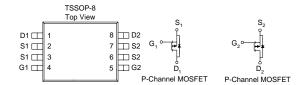
P-Channel 20-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

•	Low r _{DS(on)} provides higher efficiency and
	extends battery life

- Low thermal impedance copper leadframe TSSOP-8 saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY				
$V_{DS}(V)$	$r_{DS(on)}$ (OHM)	$I_{D}(A)$		
	0.050	-4.0		
-20	$0.060 @ V_{GS} = -2.5V$	-3.6		
	$0.075 @ V_{GS} = -1.8V$	-3.2		



ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Maximum	Units	
Drain-Source Voltage			-20	V	
Gate-Source Voltage		V_{GS}	±8	V	
	$T_A=25^{\circ}C$	т	-4.0		
Continuous Drain Current ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	1D	-3.2	A	
Pulsed Drain Current ^b		I_{DM}	-10		
Continuous Source Current (Diode Conduction) ^a		I_S	±1.6	A	
D a	$T_A=25^{\circ}C$	D	1.15	W	
Power Dissipation ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	rD	0.7	VV	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	-55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Тур	Max	
Mariana Innation to Analizata	t <= 10 sec	D	93	110	0C/W
Maximum Junction-to-Ambient ^a	Steady State	R_{thJA}	130	150	°C/W

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Parameter	C11	T4 C14	Limits			T T24
Farameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static						
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = -250 \text{ uA}$	-0.40			
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = +/-12 \text{ V}$			±100	nA
Zero Gate Voltage Drain Current	$I_{ m DSS}$	$V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V}$			-1	uA
Zero Gate Voltage Drain Current	1DSS	$V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			-10	
On-State Drain Current ^A	I _{D(on)}	$V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$	-3			A
		$V_{GS} = -4.5 \text{ V}, I_D = -4.0 \text{ A}$			0.050	
Drain-Source On-Resistance ^A	$r_{DS(on)}$	$V_{GS} = -2.5 \text{ V}, I_D = -3.6 \text{ A}$			0.060	Ω
		$V_{GS} = -1.8 \text{ V}, I_D = -3.2 \text{ A}$			0.075	
Forward Tranconductance ^A	g_{fs}	$V_{DS} = -5 \text{ V}, I_{D} = -4.0 \text{ A}$		3		S
Diode Forward Voltage	V_{SD}	$I_S = -1.6 \text{ A}, V_{GS} = 0 \text{ V}$		-0.70		V
Dynamic ^b						
Total Gate Charge	Q_{g}	$V_{DS} = -5 \text{ V}, V_{GS} = -4.5 \text{ V},$		12.2		nC
Gate-Source Charge	Q_{gs}	$V_{DS} = -3 V, V_{GS} = -4.5 V,$ $I_{D} = -4.0 A$		1.1		
Gate-Drain Charge	Q_{gd}	I _D = -4.0 A		1.5		
Turn-On Delay Time	$t_{d(on)}$			6.5		
Rise Time	$t_{\rm r}$	$V_{DD} = -5 \text{ V}, R_L = 5 \text{ OHM},$		20		ns
Turn-Off Delay Time	$t_{d(off)}$	$V_{GEN} = -4.5 \text{ V}, R_G = 6 \text{ OHM}$		31		115
Fall-Time	t_{f}			21		

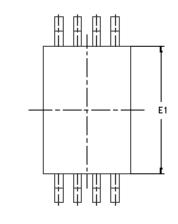
Notes

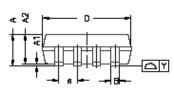
- a. Pulse test: $PW \le 300us duty cycle \le 2\%$.
- b. Guaranteed by design, not subject to production testing.

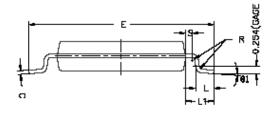
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Package Information

TSSOP-8: 8LEAD







DIM.	MILLIMETERS				
	MIN.	NDM.	MAX.		
A	1.05	1.10	1.20		
A(1)	0.05	0.10	0.15		
A(2)	g.99	1.02	1.05		
В	D.19	0.25	0.30		
С		0.127			
D	2.90	3.0D	3.10		
Ε	6.20	6.40	6.60		
E1	4.30	4.40	4.50		
В	0.659SC				
L	0.45	0.60	0.75		
L1	0.90	1.00	1.10		
Y			0.10		
8 1	07	4	6		
R	D.09				
S	0.20				